TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74HCT08AP,TC74HCT08AF,TC74HCT08AFN

### Quad 2-Input AND Gate

The TC74HCT08A is a high speed CMOS 2-INPUT AND GATE fabricated with silicon gate  $C^2MOS$  technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

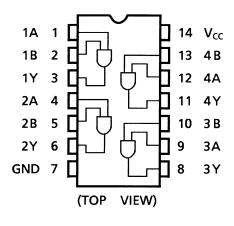
The internal circuit is composed of 4-stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

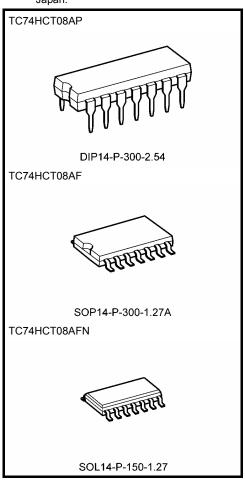
#### **Features**

- High speed:  $t_{pd} = 10 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 1 \mu A \text{ (max)}$  at  $T_{a} = 25 \text{°C}$
- Compatible with TTL outputs:  $V_{IH}$  = 2 V (min)  $V_{IL}$  = 0.8 V (max)
- Wide interfacing ability: LSTTL, NMOS, CMOS
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with 74LS08

#### **Pin Assignment**



Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) SOL14-P-150-1.27 : 0.12 g (typ.)

#### **IEC Logic Symbol**

1A (1)	&	(3)
1B (2)	ų.	1Y
2A (4)		<i>(E</i> )
(5)		(6) 2Y
ZB (9)		(0)
3A (10)		(8) 3Y
(12)		(4.4)
4A (13)		(11) 4Y
4B —(13)		

#### **Truth Table**

Α	В	Υ
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

## **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5~7	V
DC input voltage	V <sub>IN</sub>	-0.5~V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5	V
Input diode current	l <sub>IK</sub>	±20	mA
Output diode current	Іок	±20	mA
DC output current	Гоит	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	−65 <b>~</b> 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta =  $-40 \text{ to } 65^{\circ}\text{C}$ . From Ta =  $65 \text{ to } 85^{\circ}\text{C}$  a derating factor of  $-10 \text{ mW}/^{\circ}\text{C}$  shall be applied until 300 mW

#### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5~5.5	V
Input voltage	V <sub>IN</sub>	0~V <sub>CC</sub>	V
Output voltage	Vout	0~V <sub>CC</sub>	٧
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0~500	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



## **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol		Test Condition $V_{CC}\left(V\right)$		-	Га = 25°C		Ta = -40~85°C		Unit	
				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
High-level input voltage	$V_{IH}$	_		4.5~5.5	2.0	_		2.0	_	٧
Low-level input voltage	$V_{IL}$	_		4.5~5.5	_	_	0.8	_	0.8	٧
High-level output	Vou	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -20 \mu A$	4.5	4.4	4.5		4.4	_	V
voltage	VOH		I <sub>OH</sub> = -4 mA	4.5	4.18	4.31	_	4.13	_	
Low-level output	V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	V
voltage			I <sub>OL</sub> = 4 mA	4.5	_	0.17	0.26	_	0.33	V
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μΑ
	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	1.0	_	10.0	μА
Quiescent supply current IC		Per input: $V_{IN} = 0.5 \text{ V or } 2.4 \text{ V}$ Other input: $V_{CC}$ or GND		5.5	_	_	2.0	_	2.9	mA

## AC Characteristics ( $C_L = 15 \text{ pF}$ , $V_{CC} = 5 \text{ V}$ , $Ta = 25^{\circ}\text{C}$ , input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub>	_	_	6	12	ns
	t <sub>THL</sub>					
Propagation delay time	t <sub>pLH</sub>	_	_	10	16	ns
	t <sub>pHL</sub>			10	10	113

#### AC Characteristics ( $C_L = 50 \text{ pF}$ , input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Test Condition		-	Ta = 25°C	)	Ta = -40~85°C		Unit
	Зупроі		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
Output transition time	t <sub>TLH</sub>	_	4.5	_	8	15	_	19	ns
Output transition time	t <sub>THL</sub>		5.5	_	7	13	_	16	
Propagation delay	$t_{pLH}$	_	4.5	_	13	20	_	25	ns
time	$t_{pHL}$		5.5		11	18	_	23	
Input capacitance	C <sub>IN</sub>			_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub>				24				pF
	(Note)				24				þΓ

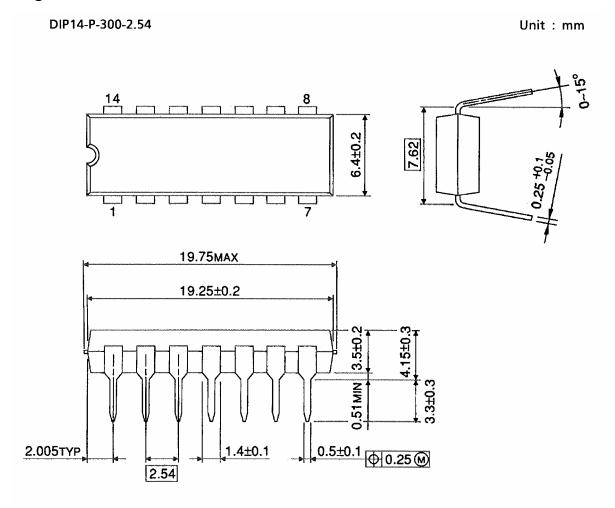
Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$  (per gate)

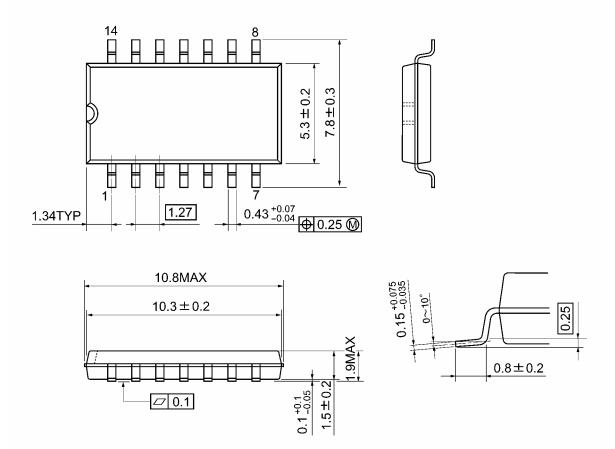
# **Package Dimensions**



Weight: 0.96 g (typ.)

# **Package Dimensions**

SOP14-P-300-1.27A Unit: mm

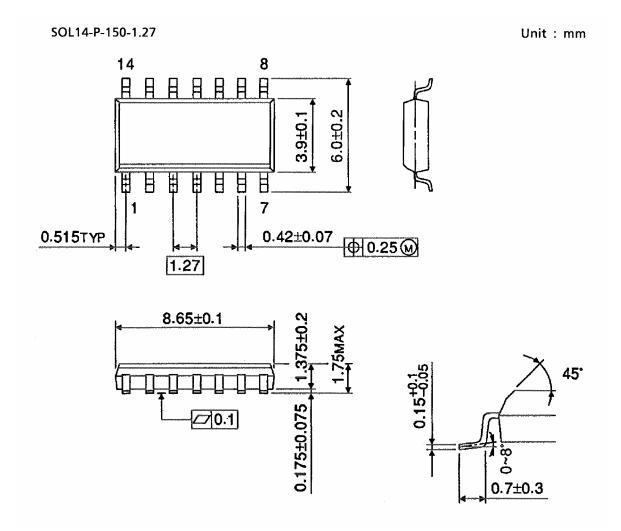


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Weight: 0.18 g (typ.)



# **Package Dimensions (Note)**



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Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

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20070701-EN GENERAL

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